



60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
001/	2Ω @ V _{GS} = 10V	343mA
60V	3Ω @ V _{GS} = 5V	284mA

Features and Benefits

- Low On-Resistance: R_{DS(ON)}
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN601TKQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Power-management functions

Mechanical Data

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

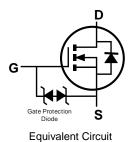


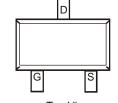


SOT523



Top View





Top View Pin Out Configuration

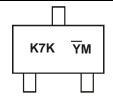
Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Number	Fackaye	Qty.	Carrier	
DMN601TKQ-7	SOT523	3,000	Tape & Reel	
DMN601TKQ-13	SOT523	10,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K7K = Product Type Marking Code YM = Date Code Marking \overline{Y} = Year (ex: K = 2023) M = Month (ex: 9 = September)

Date Code Kev

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	Р	R	S	T	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	60	V		
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	lο	343 274	mA		
Maximum Continuous Body Diode Forward Currer	Is	300	mA		
Pulsed Drain Current (10μs Pulse, Duty Cycle = 19	%)		Ірм	1	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.4	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	326	°C/W
Total Power Dissipation (Note 6)		PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	253	°C/W
Operating and Storage Temperature Range	·	TJ, TSTG	-55 to +150	°C

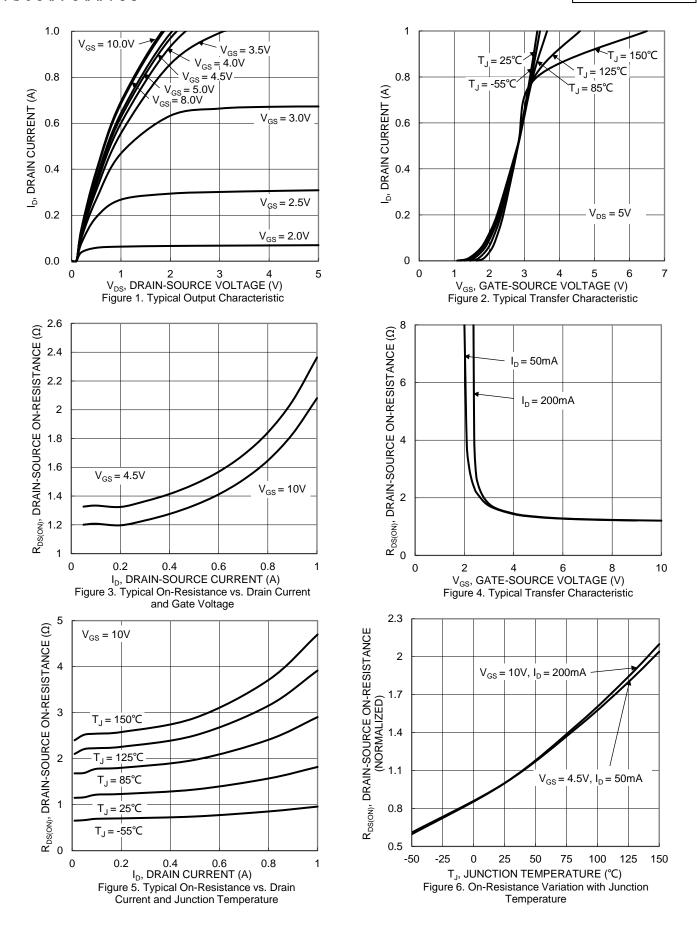
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					<u> </u>	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	1.0	μΑ	V _{DS} = 60V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	1.0	_	2.5	V	$V_{DS} = 10V$, $I_D = 1mA$
Static Drain-Source On-Resistance	PDC/ON)		1.2	2.0	Ω	$V_{GS} = 10V, I_{D} = 200mA$
Static Dialif-Source Off-Nesistance	RDS(ON)		1.3	3.0	32	$V_{GS} = 5V$, $I_D = 50mA$
Diode Forward Voltage	V_{SD}		8.0	1.2	V	$V_{GS} = 0V, I_{S} = 0.05A$
DYNAMIC CHARACTERISTICS (Note 8)	•					
Input Capacitance	Ciss	_	41	_	pF	1/ 201/ 1/ 01/
Output Capacitance	Coss	—	4.5	_	pF	V _{DS} = 30V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.7	_	pF	1 – 1.0101112
Gate Resistance	R_g		224	_	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge (Vgs = 4.5V)	Q_g		0.51	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	1.04	_	nC	\/-
Gate-Source Charge	Qgs	_	0.16	_	nC	$V_{DS} = 15V, I_{D} = 200mA$
Gate-Drain Charge	Qgd	_	0.18	_	nC	
Turn-On Delay Time	tD(ON)	_	6.9	_	ns	
Turn-On Rise Time	t _R	_	5.8	_	ns	V _{DD} = 30V, V _{GS} = 10V,
Turn-Off Delay Time	t _{D(OFF)}	_	37.8	_	ns	$R_G = 150\Omega$, $I_D = 200mA$
Turn-Off Fall Time	tF	_	14.3	_	ns	

Notes:

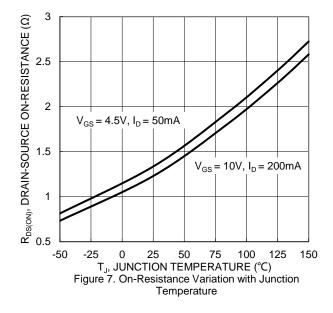
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.

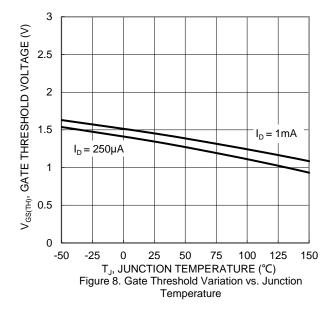


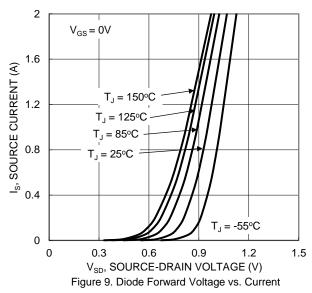


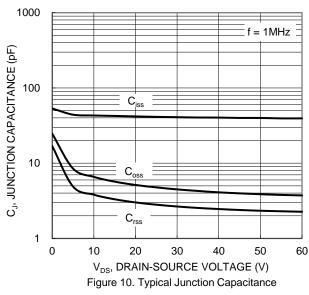


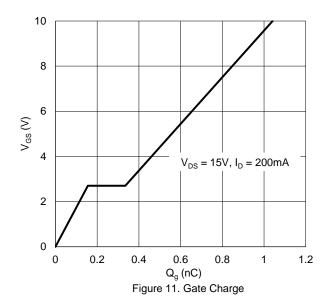


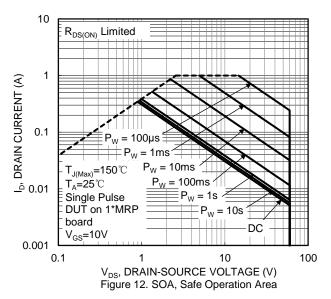




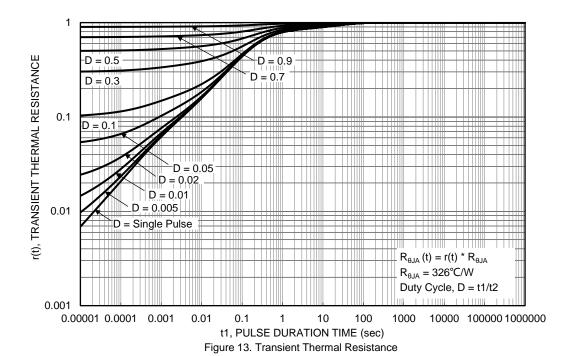










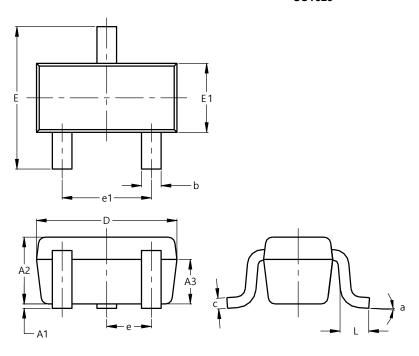




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

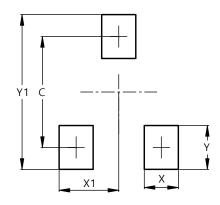


SOT523						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.60	0.80	0.75			
A3	0.45	0.65	0.50			
b	0.15	0.30	0.22			
С	0.10	0.20	0.12			
D	1.50	1.70	1.60			
E	1.45	1.75	1.60			
E1	0.75	0.85	0.80			
е	0.50 BSC					
e1	0.90	1.10	1.00			
L	0.20	0.40	0.33			
а	0°		8°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Υ	0.51
V1	1.80



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